NSN 5962-01-176-0035

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inche	s and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Di	ssipation Rating:
794.0 milliwatts	
Operating Tempura	ture Range:
-55.0/+125.0 degrees	s celsius
Storage Tempuratu	re Range:
-65.0/+150.0 degrees	s celsius
Features Provided:	
Hermetically sealed a	and programmable and bipolar and monolithic
Inclosure Material:	
Ceramic and glass	
Inclosure Configura	tion:
Dual-in-line	
Output Logic Form:	
Transistor-transistor	ogic
Input Circuit Patteri	n:
10 input	
Case Outline Sourc	e And Designator:
D-2 mil-m-38510	
Terminal Surface Tr	eatment:
Solder	
Voltage Rating And	Type Per Characteristic:
-0.5 volts power sou	rce and 7.0 volts power source
Time Rating Per Ch	acteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	e:
Prom	
Memory Capacity:	
Unknown	
Terminal Type And	Quantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	

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